

Theme 3: Packaging and Integration 7-4-2014

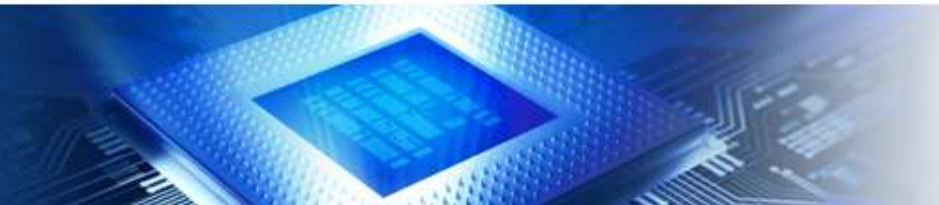
Lee Empringham, Mark Johnson,
Rasha Saeed, Jordi Espina

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Scope of Theme

- Power Module integration / packaging
- The use of basic (low-level) components, such as dies, substrates etc.
- Co-design of electromagnetic, mechanical and thermal properties
- Modular design for scalable power
- Implementation of promising technologies such as: SiC, Ag nano flakes sintering, Jet impingement / turbulator cooling
- Embedded filters and integrated gate drive



Main Team Members

- Prof Mark Johnson
- Dr Lee Empringham
- Ms Rasha Saeed
- Dr Jordi Espina (Demonstrators)



Power Module Aims

- Increased Power density
 - Without compromising on efficiency
 - Use of SiC devices – pros and cons
 - Reduce EMI
 - Integrated filtering
 - Integrated control
-
- Power Electronic Building Block?? (PEBB)

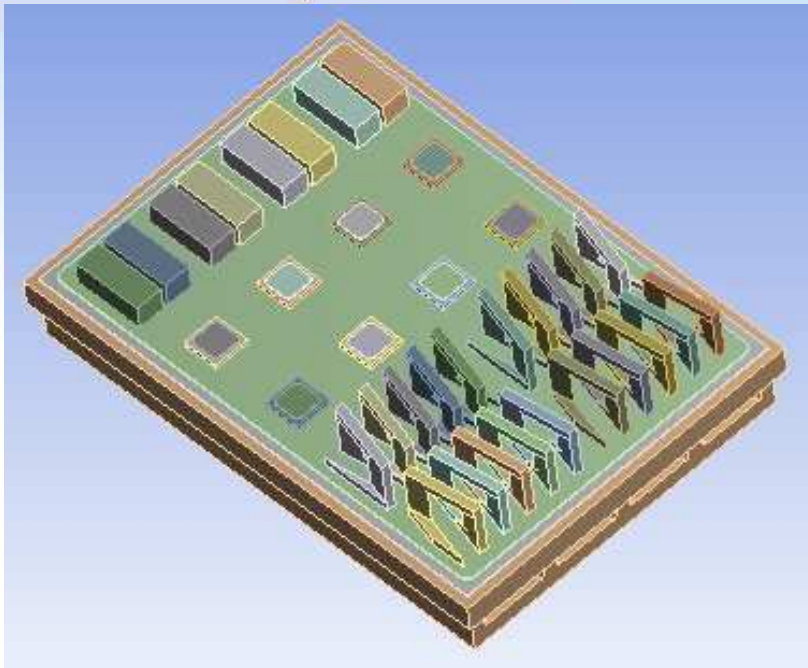


VESI Power Module Vision

- Multi cellular approach to high power
 - Multiple smaller switching cells
 - Reduced commutation loops
 - System performance (overshoot / EMI) ensured by physical design
- Integrated output Inductances
 - Reduced EMI
 - High Frequency interleaved operation
- Integrated Cooling



Power module concept



- Multiple commutation cells per module
 - Input Capacitance, active devices, output inductance
 - Parallel output connection
 - Modular choice of power ratings using standard building block
 - Interleaved operation



Recent Activities

- Circuit simulations – EMI / switching behaviour comparison of VESI modular topology with traditional power module
- Integrated inductance optimisation matrix
- Validation of inductance calculations using Ansys
- Inductor Manufacturing tests
- Tri-metal device coating tests



Inductance Optimisation Spreadsheet

- Excel spreadsheet used to determine the different parameters of the integrated inductances
- Aim is to be able to perform a trade-off and quickly determine the limiting factors when trying to maximise
 - Inductance
 - Energy density
 - Efficiency



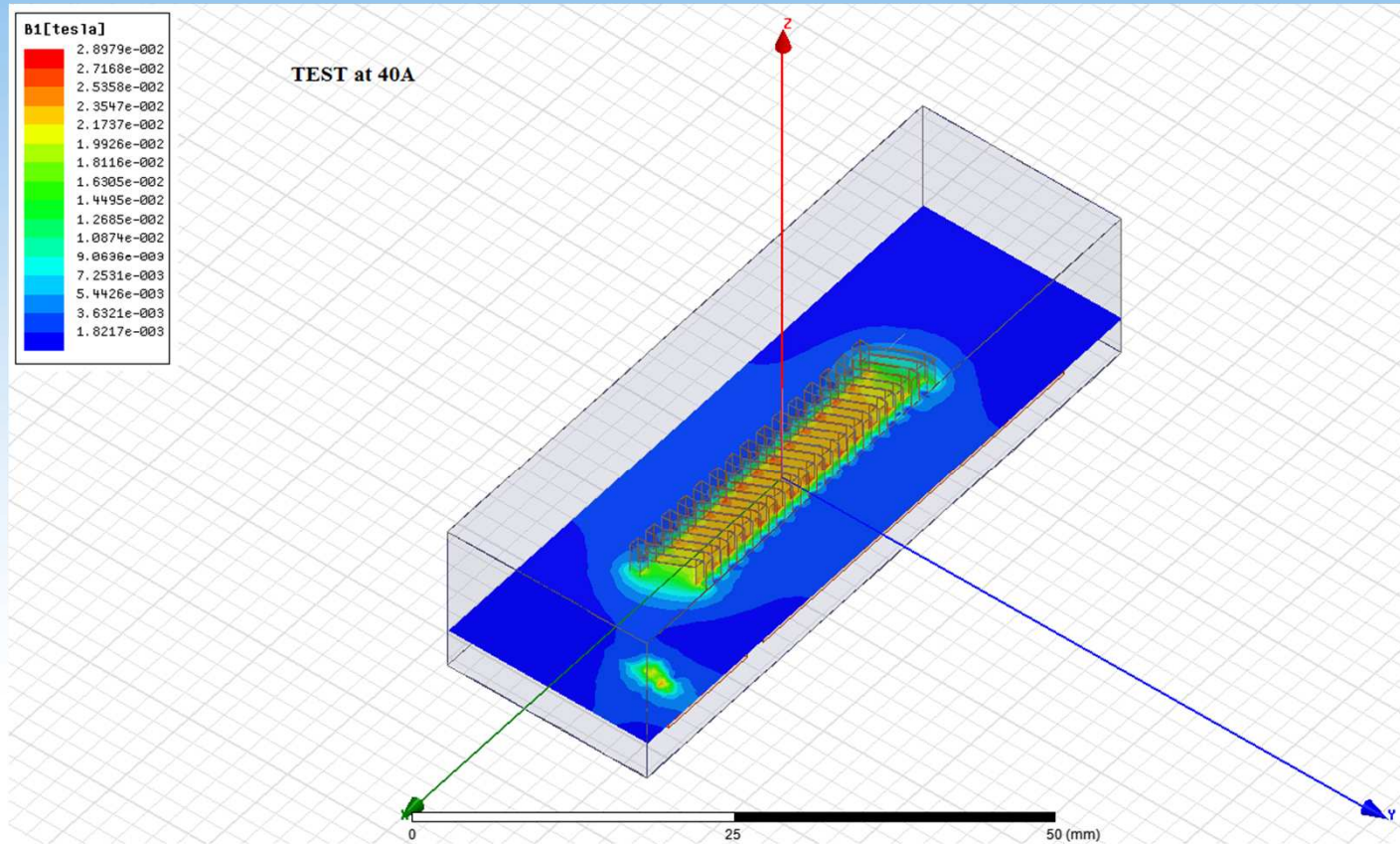
Inductance Optimisation Spreadsheet

inductor 1				Inductance (μH)	Flux density	Inductance	energy density	
N turn=16		Coil Length=31 mm						
x	y	z	q	40A	0.24	0.03	314000	251.2
6mm	6mm	4mm	4mm	20A	0.24	0.01	309677	62.8

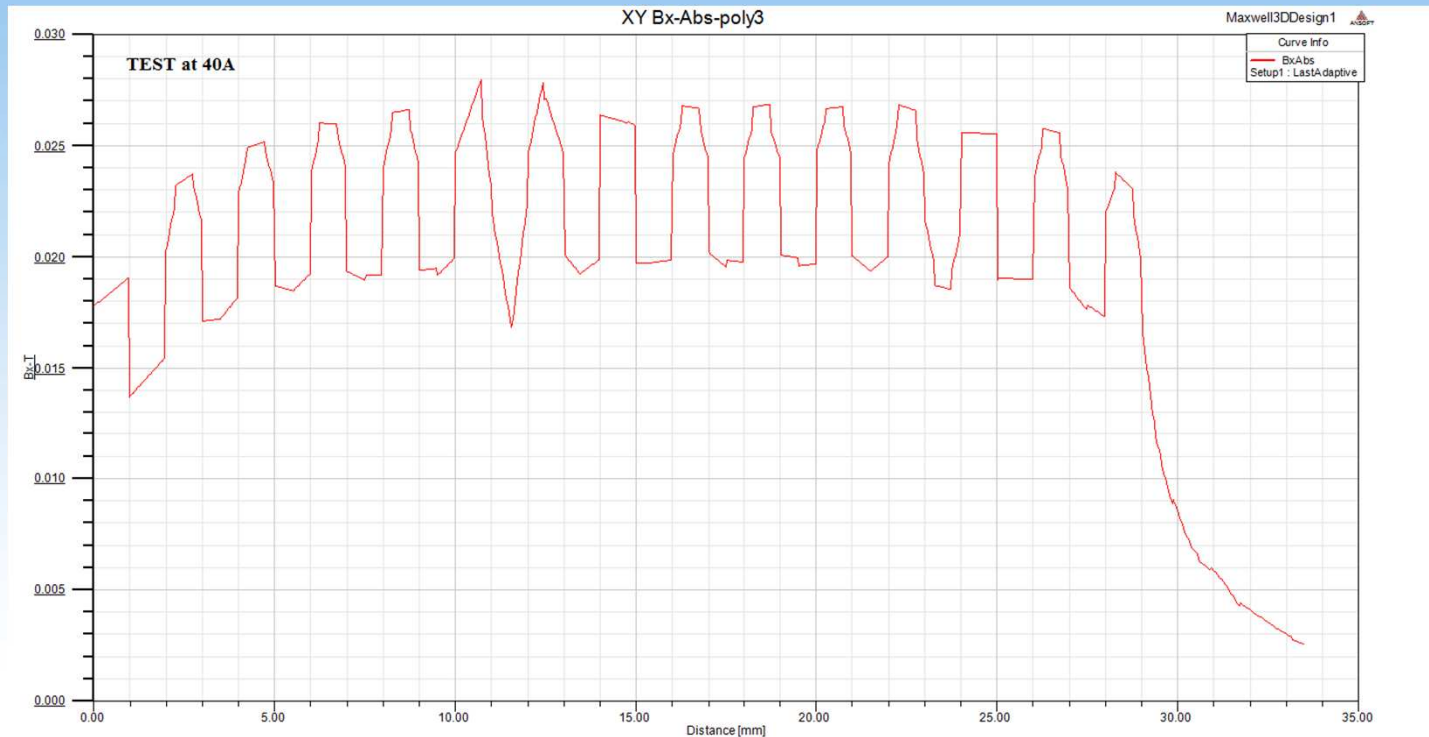
- Different inductor geometries addressed
- Linear approximations used
- Both air cored and cored inductances (metglas, ferrite)



Ansys B – Field results (Air cored @ 40A)



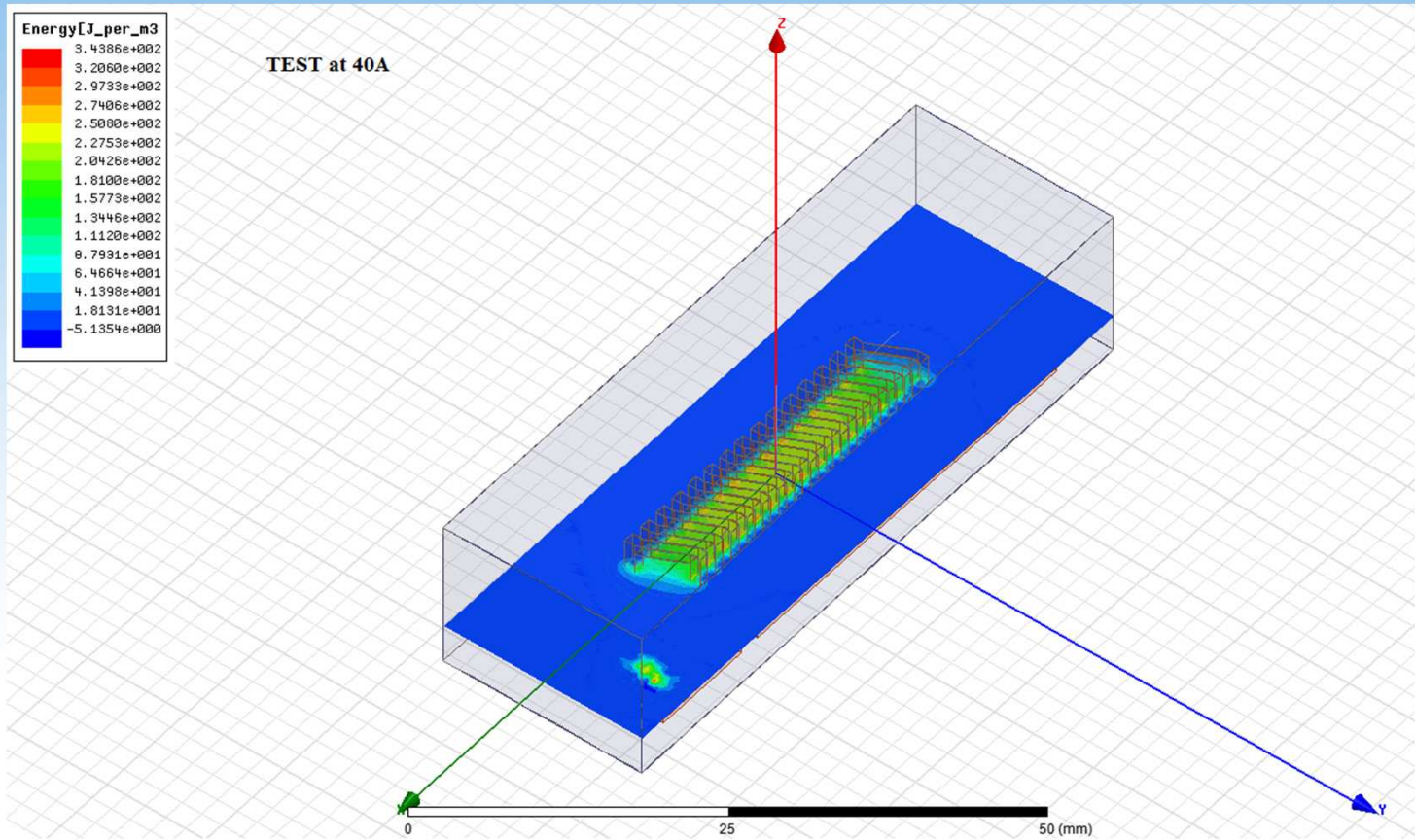
B – Field (x slice) results (Air cored @ 40A)



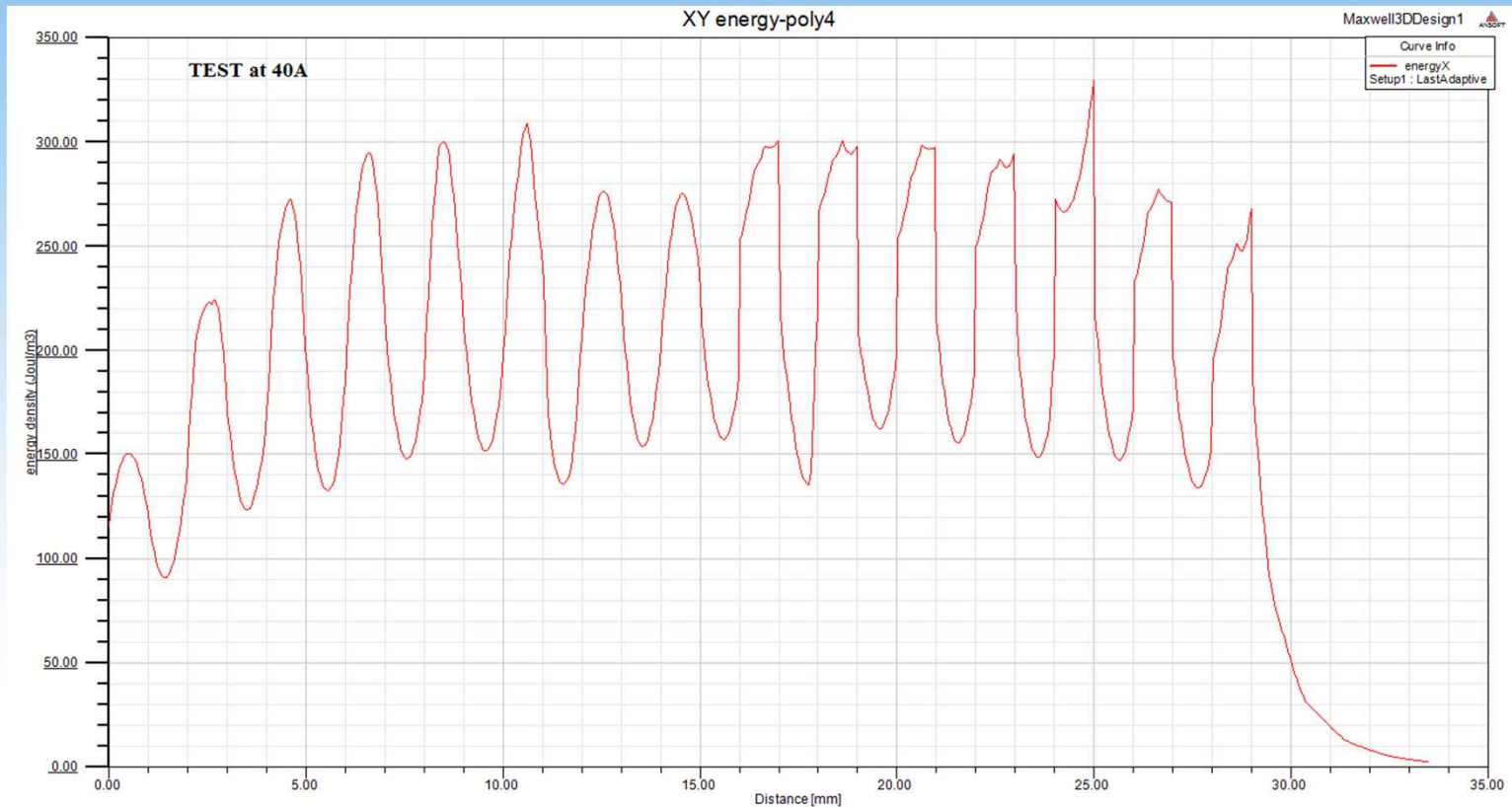
- Spreadsheet average value prediction – 0.03



Energy Density results (Air cored @ 40A)



B – Field (x slice) results (Air cored @ 40A)

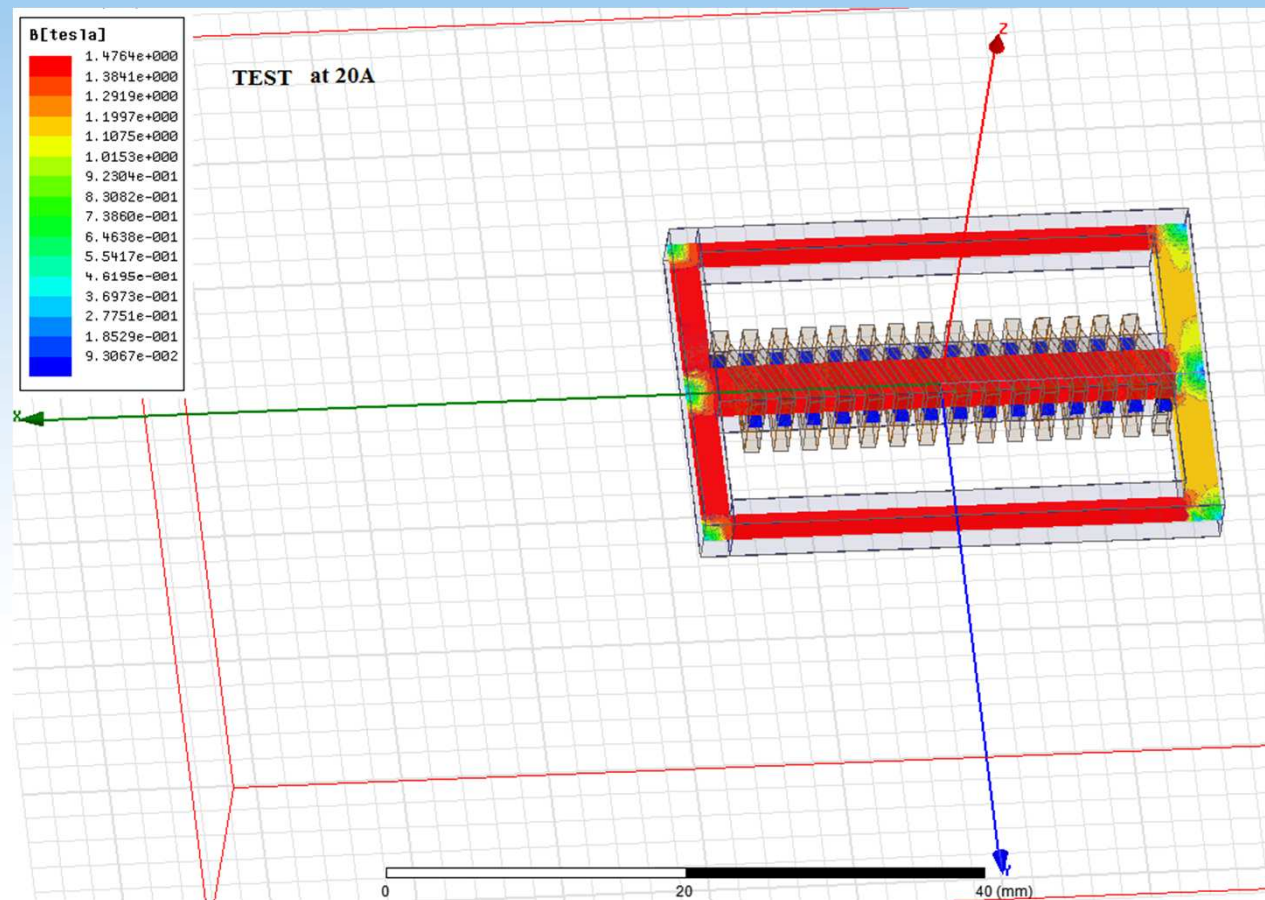


- Spreadsheet average value prediction – 251 J/m^3



Initial results using Metglas 2605S3A HFA core (20A)

- Test at 20A significant saturation (B-Max = 1.41T)

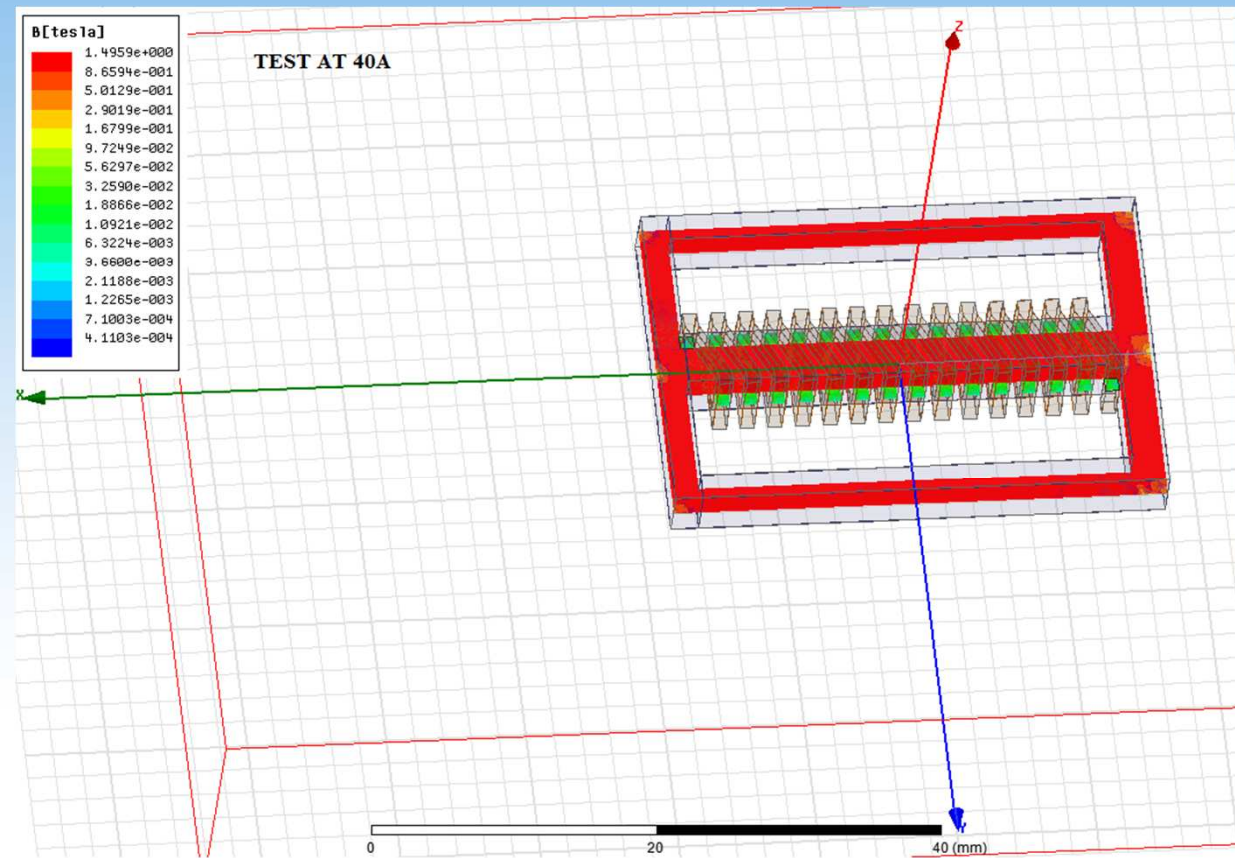


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Initial results - Metglas 2605S3A HFA core

- Test at 40A shows complete saturation

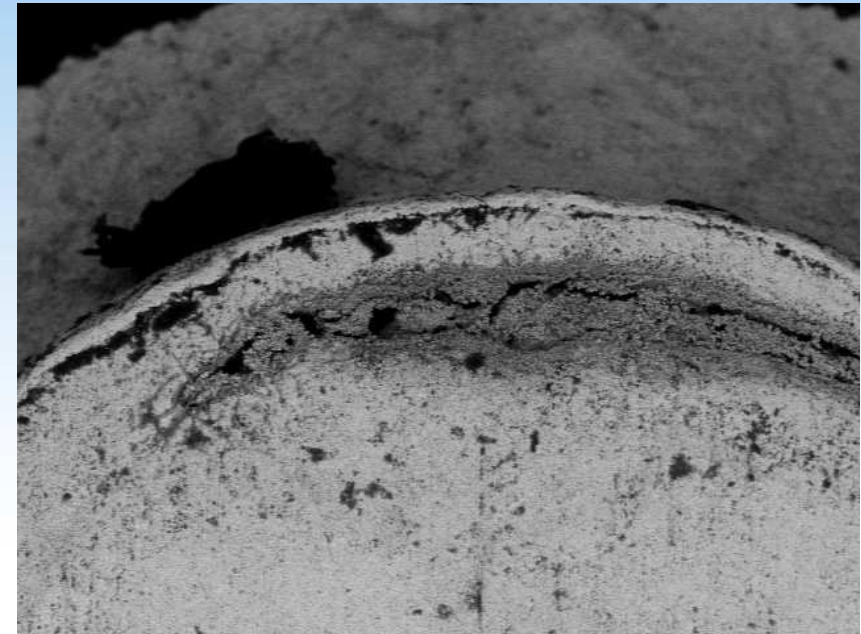


Inductor Manufacturability tests

- PCB type approach tested – 1mm solid pins, 0.3mm surface thickness.



TM3000_1168 2014/04/04 15:15 AL D6.0 x40 2 mm



TM3000_1171 2014/04/04 15:17 AL D6.0 x300 300 um

Significant voids observed



Next steps

- Continue to investigate SiC devices using solderable drain connections
- Continue to explore inductor trade off when core is used
 - Efficiency – Inductance – Volume
- Continue manufacturing investigations
 - Inductors
 - Tri-metal coating of SiC devices